

## **PN3567**

## **NPN General Purpose Amplifier**

- This device is for use as a medium amplifier and switch requiring collector currents up 300mA.
- Sourced from process 19.



### 1. Emitter 2. Base 3. Collector

## Absolute Maximum Ratings $T_A=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CEO</sub>	Collector-Emitter Voltage	40	V
V <sub>CBO</sub>	Collector-Base Voltage	80	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
I <sub>C</sub>	Collector Current - Continuous	600	mA
T <sub>J,</sub> T <sub>STG</sub>	Operating and Storage Junction Temperature Range	- 55 ~ 150	°C

## **Electrical Characteristics** $T_A=25$ °C unless otherwise noted

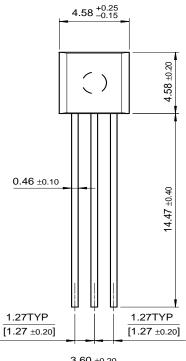
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
Off Chara	Off Characteristics					
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage *	$I_C = 30 \text{mA}, I_B = 0$	40			V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	$I_C = 100 \mu A, I_E = 0$	80			V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = 10\mu A, I_C = 0$	5			V
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB} = 40V, I_{E} = 0$			50	nA
		$V_{CB} = 40V, I_{E} = 0, T_{A} = 75^{\circ}C$			5	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = 4V, I_{C} = 0$			25	nA
On Characteristics						
h <sub>FE</sub>	DC Current Gain	V <sub>CE</sub> = 1V, I <sub>C</sub> = 150mA	40		120	
		$V_{CE} = 1V, I_{C} = 30mA$	40			
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage *	I <sub>C</sub> = 150mA, I <sub>B</sub> = 15mA			0.25	V
V <sub>BE</sub> (on)	Base-Emitter On Voltage	V <sub>CE</sub> = 1V, I <sub>C</sub> = 150mA			1.1	V
Small Signal Characteristics						
C <sub>obo</sub>	Output Capacitance	$V_{CB} = 10V, I_{E} = 0$			20	рF
C <sub>ibo</sub>	Input Capacitance	$V_{EB} = 0.5V, I_{C} = 0$			80	

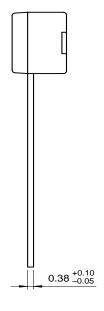
<sup>\*</sup> Pulse Test: Pulse Width ≤ 300ms, Duty Cycle ≤ 2.0%

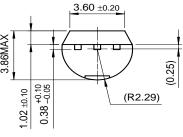
Symbol	Parameter	Max.	Units
$P_D$	Total Device Dissipation Derate above 25°C	625 5	mW mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	83.3	°C/W
$R_{\theta JC}$	Thermal Resistance, Junction to Case	200	°C/W

# **Package Dimensions**

TO-92







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